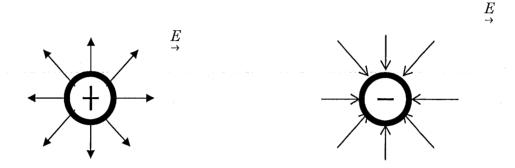
FLUX OF E- FIELD: GAUSS' LAW

We have used the analogy of water flowing into (out of) a sink (source) to imagine the E- field surrounding a point charge.



Just as we talk of the amount of water flowing through an area, we now talk of the FLUX of E as the quantity

$$\Delta \Phi_E = E \bullet \Delta A = E \Delta A \ Cos(E, \hat{n})$$

as a measure of the "amount" of E- field "flowing" out of or into a surface of area $\Delta A = \Delta A \hat{n}$ Example

Take area
$$\Delta A$$
 lying in xy-plane
 $\Delta A = \Delta A \hat{n}$
 $= \Delta A \hat{z}$

Take
$$E = E_y \hat{y} + E_z \hat{z}$$

\hat{n} $E \rightarrow AAA$

NOTICE:

FLUX Is MAXIMUM when $E \parallel \hat{n}$.

FLUX Is ZERO when $E \perp \hat{n}$

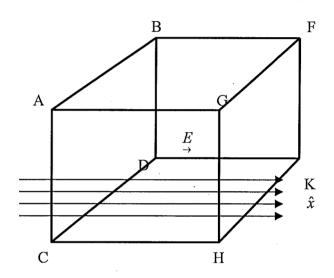
Thus

$$\Delta \Phi_E = E \Delta A Cos(E, \hat{z})$$
or
$$\Delta \Phi_E = (\Delta A)E_z$$

That is only component of E parallel to \hat{z} contributes to flux of E through ΔA . [To go through a door you must travel along its normal]

Example:

Consider a cube. Let $E = E\hat{x}$



NO SOURCE OR SINK INSIDE CUBE

Flux of E is non-zero only over faces ABCD and FGHK.

Over ABCD flux is into Cube

Over FGHK flux is out of Cube

TOTAL FLUX THROUGH CUBE=0 AS IT MUST BE BECAUSE THERE IS NO SOURCE OR SINK INSIDE IT. EVERY LINE THAT COMES IN MUST LEAVE [LINES STOP (START) AT SINKS (SOURCES) ONLY].

So it is not surprising that Gauss' Law says: THE TOTAL FLUX OF THE E-FIELD

THROUGH A CLOSED SURFACE IS DETERMINED SOLELY BY THE SOURCES (+CHARGES) AND SINKS (-CHARGES) IN THE VOLUME ENCLOSED BY THE SURFACE.

Mathematically,
$$\Sigma_c \stackrel{E \bullet}{\to} \Delta A = \Sigma_c E \perp \Delta A = \frac{1}{\varepsilon_0} \Sigma Q i$$

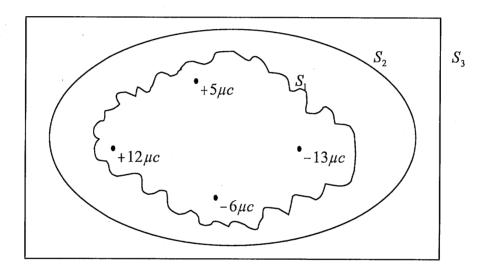
Where $\frac{1}{4\pi\varepsilon_0} = k_e = 9x10^9 \frac{N - m^2}{c^2}$, $\varepsilon_0 = 9x10^{-12} \frac{F}{m}$

The \sum_{c} on the left hand side is sum of the flux over <u>all</u> parts of the closed surface. $\sum_{c} Q_{i}$ is the algebraic sum of all the enclosed charges.

Example:

In general, Gauss' law would be very difficult to use to calculate E. All it can give us is the total flux once the Q_i 's are known. Here are 4 charges. If you draw any surface enclosing all of them we can write down the total flux of E immediately.

 S_1, S_2, S_3 are any three closed surfaces drawn around our four charges. In each case



$$\Sigma_c \stackrel{E \bullet}{\to} \stackrel{\Delta A}{\to} = \frac{1}{9 \times 10^{-12}} \left[5 \times 10^{-6} + 12 \times 10^{-6} - 6 \times 10^{-6} - 13 \times 10^{-6} \right]$$
$$= -2.2 \times 10^5 \frac{N - m^2}{C}$$

but it tells you nothing about the E-field at any point on any surface.

However, there are some special cases where we can use this law to calculate Efield in one step. [Please look at notes from Phys 121 to recall similar results for Gravitational field.]

The calculation depends crucially on recognizing the symmetry of the problem and choosing the Gaussian Surface in such a way that the sum on the left of Eq. I can be calculated right away.

Example 1:

Point charge +Q located at the origin, r=0. Because of spherical symmetry about r=0, the E-field cannot depend on angle. It must be radial (along \hat{r}) and be a function of r only. We should choose for our surface a sphere of radius r centered at r=0. Then I) E has the same magnitude at all points on the surface of the sphere and II)

$$E \stackrel{\bullet}{\rightarrow} \Delta A = E(r) 4\pi r^2 = \frac{Q}{\varepsilon_0}$$

because

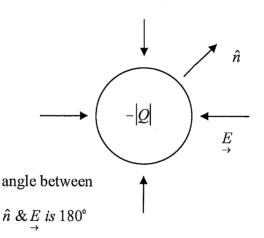
 $E \parallel \hat{r}$ everywhere so $E \bullet \hat{n} = E$

$$E = \frac{Q}{4\pi\varepsilon_0 r^2} \hat{r} = \frac{k_e Q}{r^2} \hat{r}$$

Example 2:

-|Q| Located at r=0. Again E can only be a function of r and directed along

 $-\hat{r}$ so (FLUX is inward) $-E \cdot 4\pi r^2 = \frac{-|Q|}{4\pi\varepsilon_0}$



$$E(r) = \frac{-|Q|}{4\pi\varepsilon_0}r$$

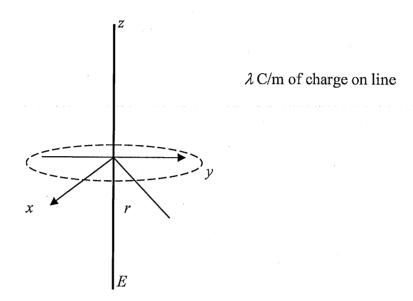
Example 3:

Long Line of charge: λ C/m along \hat{z} . Now there is cylindrical symmetry about z-axis.

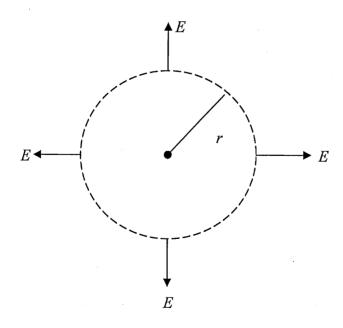
Field cannot depend on z.

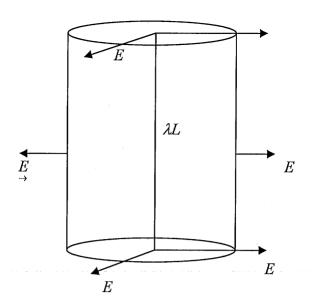
Field cannot depend on Angle.

Must be a fn of r only and directed along r.



Choose as surface cylinder of length L, radius r, axis of cylinder on z-axis. Then $\Sigma_c \overset{E \bullet}{\to} \Delta A = E(r) 2\pi r L$. No contribution from End surfaces as $\overset{E}{\to}$ is parallel to them.





Also

$$\sum Q_i = \lambda L$$

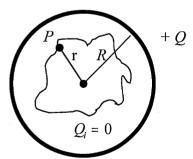
SO

$$E(r) \cdot 2\pi r L = \lambda L$$

$$E(r) = \frac{\lambda}{2\pi r \varepsilon_0} \hat{r}$$

Example 4:

Hollow sphere (spherical shell) has charge +Q on its surface, radius R and is centered at r=0. Again symmetry about r=0, requires that $E||\hat{r}|$ and is a function r only.



First, consider r < R. Choose any surface through r. r < R $\sum_{c} E \cdot \Delta A = 0 \rightarrow$ No enclosed charge.

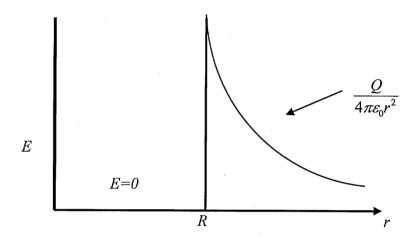
If $\sum_{c} E \cdot \Delta A = 0$ for any and every surface as long as r < R, it implies E = 0

If r>R; the appropriate surface is a sphere of radius r and now $\sum_{c} E \bullet \Delta A = E(r) 4\pi r^2$ Hence,

$$E = \frac{Q}{4\pi\varepsilon_0 r^2} \hat{r}$$
$$= \frac{k_e Q}{r^2} \hat{r}$$
$$r > R$$

as if the shell were replaced by a single charge Q located at its center (r=0). That is, r must be measured from the center of the shell.

Sph. Shell: Q on shell



<u>Note</u>: As one goes from r < R to r > R, the E-field jumps by

$$E = \frac{Q}{4\pi\varepsilon_0 r^2}$$

$$= \frac{\sigma}{\varepsilon_0}$$

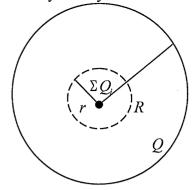
$$\left[\sigma = \frac{Q}{4\pi r^2}\right]$$

Where $\sigma =$ charge density on the surface of the shell. Crossing a sheet of charge E jumps!

Ex5: Insulating Solid Sphere

Charge Q distributed uniformly over a sphere of radius R which is located with its center at r=0. First define charge density $\rho = \frac{Q}{\frac{4\pi}{3}R^3}$ $\left[\rho = Rho\right]$

Again, spherical symmetry obtains about r=0.



Now, if *r*<*R*.

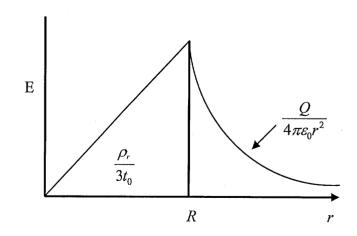
$$\sum_{c} E \cdot \Delta A = E(r) 4\pi r^{2}$$

$$\sum_{c} Q_{i} = \rho \cdot \frac{4\pi}{3} r^{3}$$
so for $r < R$.
$$E(r) 4\pi r^{2} = \frac{\rho}{\varepsilon_{0}} \cdot \frac{4\pi}{3} r^{3}$$

$$E = \frac{\rho}{3\varepsilon_{0}} r \hat{r} \qquad r < R$$

If r > R all of Q contributes so

$$E = \frac{Q}{4\pi \, \varepsilon_0 r^2} \hat{r} \qquad r > R$$



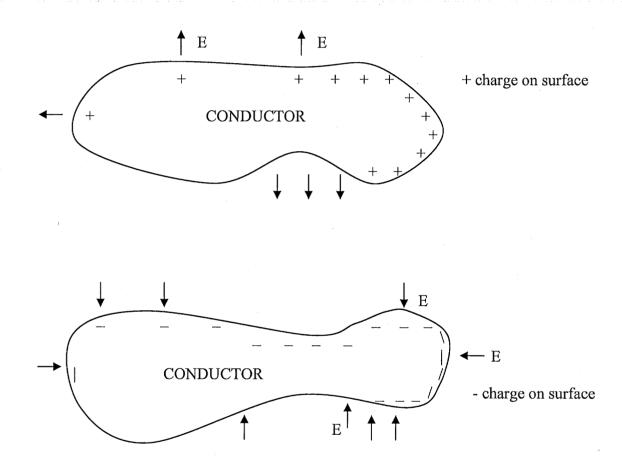
INSULATING SPHERE UNIFORMLY CHARGED with
$$\rho = \frac{Q}{\frac{4\pi}{3}R^3}$$

Ex 6:

Conductor under stationary conditions: charge \underline{NOT} allowed to move. If charge has to be immobile the field inside must be \underline{zero} at every point. This is possible only if $\underline{Q=0}$ at every point inside the conductor. So under stationary conditions charge can reside $\underline{ONLY\ ON}$ the surface of the conductor $\underline{consequences}$:

Q on conducting sphere \equiv Hollow spherical charge

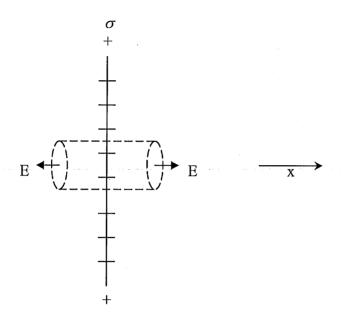
Further, E at surface must be perpendicular to surface otherwise charges will start moving along surface.



Notice: In both cases force on charge is outward, that is, charge is bound to the surface.

Ex 7:

Sheet of charge $\perp x$ -axis carries $+\sigma$ C/m^2 of charge. Sheet located at x=0. Look at it end-on Recall that we have shown if two equal charges are at +y and -y the $\stackrel{E}{\rightarrow}$ field is purely along \hat{x} .



So here E along $+\hat{x}$ on right $-\hat{x}$ on left. Choose cylinder as Gaussian Surface.

$$\Sigma_{c} \xrightarrow{E \bullet} \Delta A = E \pi r^{2} + E \cdot \pi r^{2}$$
$$= E \cdot 2\pi r^{2}$$

$$\Sigma Q_i = \sigma \pi r^2$$
 [charge enclosed by cylinder]

so

$$2E\pi r^{2} = \sigma \cdot \pi r^{2}$$

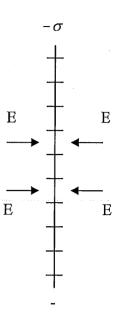
$$E = +\frac{\sigma}{2\varepsilon_{0}}\hat{x} \qquad x > 0$$

$$= -\frac{\sigma}{2\varepsilon_{0}}\hat{x} \qquad x < 0$$

Ex 7': Sheet carries $-|\sigma|C/m^2$

Then
$$E = -\frac{\sigma}{2\varepsilon_0}\hat{x} \quad x > 0$$

$$= +\frac{\sigma}{2\varepsilon_0}\hat{x} \quad x < 0$$



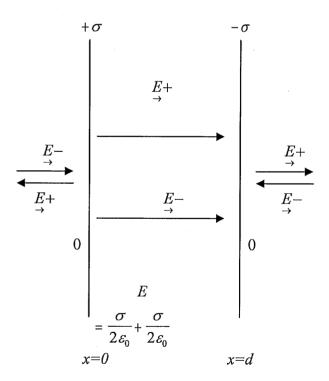
Ex 8: Sheet at x=0, $\sigma C/m^2$ Sheet at x=d, $-\sigma C/m^2$

$$E = 0, x < 0$$

$$E = \frac{\sigma}{\varepsilon_0} \quad 0 < x < d$$

$$E = 0 \quad x > d$$

Net E-field:



Now the E+ and E- fields will add vertically. Hence

 σ/ε_0 0

Again E jumps on crossing sheet of change